# PATENT COOPERATION TREATY



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P2003278E	International filing date (day/month/year)	1	30. Dec. 2002 (30/12/2002)
	24. Jul. 2003 (24/07/2003)		
International application No.	24. Jul. 2005		1
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Box No. I Ba	SIS Of the rate		entive step and industrial approaches
Box No. 1	ority	lovelty, inv	SULIA O 22-1
Box No. II Pri	sis of the report  ority  on-establishment of opinion with regard to n		a- industrial applicability;
Box No. III No	a with of invention	4 to 110	ovelty, inventive step or industrial applicability;
Box No. IV La	ick of unity of mander Article 35(2) with r	regard to in	• • • • • • • • • • • • • • • • • • • •
Box No. 1	asoned statement under Article 33(4) tations and explanations supporting such sta	atement	
Box No. V Re	diens and explanations supporting such		
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Box No. VI	Certain documents cited  Certain defects in the international applicati	ion	
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Date of submission of the	(42/07/2004)		
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## INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No.
PCT/CN03/00594

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	u		nal search (Rules 12.3(a) and 23.1(b))		
			on of the international application (Rule 12.4)	a))	
		publication	onal preliminary examination (Rules 55.2(a) a	nd/or 55.3(a))	l l
t	o the	regard to the receiving Oxed to this re	elements of the international application, thi ffice in response to an invitation under Article port):	a report is based on (replacement s	heets which have been furnished s "originally filed" and are not
1	П	the internati	onal application as originally filed/furnished		
	_	the descript			as originally filed/furnished
		pages	1-6, 8, 10-14	received by this Authority on	30. May. 2005 (30/05/2005)
		pages *	7, 9	received by this Authority on received by this Authority on	
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	⊠	the claims:		1.1 (to gother W	as originally filed/furnished ith any statement)under Article 19
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### INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No. PCT/CN03/00594

Box No. V Reasoned statement under Article 35(2) with regard to novelty, inventive step or industrial applicability; citations and explanations supporting such statement					
. Statement: Novelty (N)	Claims	1-18	YES NO		
Inventive step (IS)	Claims	2-8,12,16 1,9-11,13-15,17-18	YES NO		
Industrial applicability (IA)	Claims	1-18	YES NO		

2. Citations and explanations (Rule 70.7)

Reference is made to the following documents:

D1: US 6,251,835 B1 (26 Jun. 2001)

D2: CN 1171635 A (28 Jan. 1998)

- 1. Claim 1 lacks an inventive step according to PCT Article 33(3). D1 describes High Temperature Superconductor(HTS) surfaces Planarization, comprising the following technical features: High Temperature Superconductor(HTS) surfaces is bombarded with gas cluster ions of having energies greater than 7keV and less than 200keV (claim 1 claims 5eV-50keV which is overlapped with D1), to reduce both the surface roughness and the crystallinity of the surface and to impair the high temperature superconducting properties of said surface (see col. 3 line 44 to 61, claims 1,5). Comparing the technical solution of independent claim 1 with the summary of D1, the only difference is "an angle of incidence is between 5 and 85 degrees". D2(CN1171635A) discloses a method for removing asperitier from the surface of a high temperature superconducting thin fim (TI-Ba-Ca-Cu-O superconductor), comprising the following technical features:exposing the surface of a high temperature superconducting film to an inert ion beam at an angle of incidence of from 5 to about 30 degrees relative to the surface of the thin film, a power is 300-500V,300mA (see page 5 line 6 to page 8, claim 1). In D2, it is cerntain that ion beam have energy by bomdarded with sure power. Considering the D1 and D2, the technical solution of independent claim 1 is obvious to those skilled in the art and can not produce unexpected technical effects. Therefore the technical solution of claim 1 lacks non-obvious features and an inventive step. The claim 1 does not appear to be an inventive step.
  - 2 、Claim 9 lacks an inventive step according to PCT Article 33(3). D2 describes high temperature superconducting thin fim is TI-Ba-Ca-Cu-O superconductor (see page 5 line 7, claim 1). Therefore claim 9 lacks an inventive step.
  - 3. Claim 10 lacks an inventive step according to PCT Article 33(3). D1 discloses High Temperature Superconductor(HTS) surfaces is bombarded with gas cluster ions to reduce both the surface roughness (i.e. external)and the crystallinity (i.e. body)of the surface (see claim 1). Therefore claim 10 lacks an inventive step.

### INTERNATIONAL PRELIMINARY REPORT ON PATENTABILITY

International application No.
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### Supplemental Box

In case the space in any of the preceding boxes is not sufficient.

Continuation of:

- 4. Claim 11 lacks an inventive step according to PCT Article 33(3). D1 discloses High Temperature Superconductor(HTS) surfaces is bombarded with gas cluster ions—to reduce both the surface roughness and the crystallinity of the surface (see claim 1), i.e. HTS is single crystalline or polycrystalline. Therefore claim 11 lacks an inventive step.
- 5. Claim 13 lacks an inventive step according to PCT Article 33(3). D1 discloses High Temperature Superconductor(HTS) is deposited on single crystalline or multi-crystalline (see col. 3 Line 5 to 12). Therefore claim 13 lacks an inventive step.
- 6. Claim 14 lacks an inventive step according to PCT Article 33(3). D1 discloses the cluster beams of the gases, such as Ar, Ne, N<sub>2</sub>, O<sub>2</sub>, CO<sub>2</sub>, SF<sub>6</sub>, etc (see col. 3 Line 51 to 54). Therefore claim 14 lacks an inventive step.
- 7. Claim 15 lacks an inventive step according to PCT Article 33(3). D1 discloses that HTS film is annealed after be bombarding, the annealing temperature is 450-870°C (see col. 5 Line 23 to 38, claims 1,12-14). Therefore claim 15 lacks an inventive step.
- 8 Claim 17 lacks an inventive step according to PCT Article 33(3). D1 relates to High Temperature Superconductor(HTS), comprising the following technical features: High Temperature Superconductor(HTS) surfaces is bombarded with gas cluster ions of having energies greater than 7keV and less than 200keV, to reduce both the surface roughness and the crystallinity of the surface and to impair the high temperature superconducting properties of said surface (see col. 3 line 44 to 61,claims 1,5). Also, fig. 4 of the D1 shown is the YBCO surface appears inclined cone appearance after YBCO has been bombarded. D2(CN1171635A) discloses high temperature superconducting thin fim (TI-Ba-Ca-Cu-O superconductor), comprising the following technical features: exposing the surface of a high temperature superconducting film to an inert ion beam at an angle of incidence of from 5 to about 30 degrees relative to the surface of the thin film, a power is 300-500V,300mA (see page 5 line 6 to page 8, claim 1). In D2, it is cerntain that ion beam have energy by bomdarded with sure power. Considering the D1 and D2, the technical solution of independent claim 17 is obvious to those skilled in the art and can not produce unexpected technical effects. Therefore the technical solution of claim 17 lacks non-obvious features and an inventive step. The claim 17 does not appear to be an inventive step.
  - 9. Claim 18 lacks an inventive step according to PCT Article 33(3). D1 discloses that HTS film is annealed after be bombarding, the annealing temperature is 450-870°C (see col. 5 Line 23 to 38, claims 1,12-14). Therefore claim 18 lacks an inventive step.